## NSN 5961-01-058-7783

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.320 inches and 0.468 inches

## **Overall Diameter:**

0.440 inches

## **Function For Which Designed:**

Switching

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact-darlington connected

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-59

## **Mounting Method:**

Threaded stud

## Features Provided:

Mounting hardware

## Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

## Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 5.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: npn

## **Test Data Document:**

30003-446as177 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

3 tab, solder lug

Shelf Life:

N/a

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Demilitarization:

No

Fiig:

A110a0

